

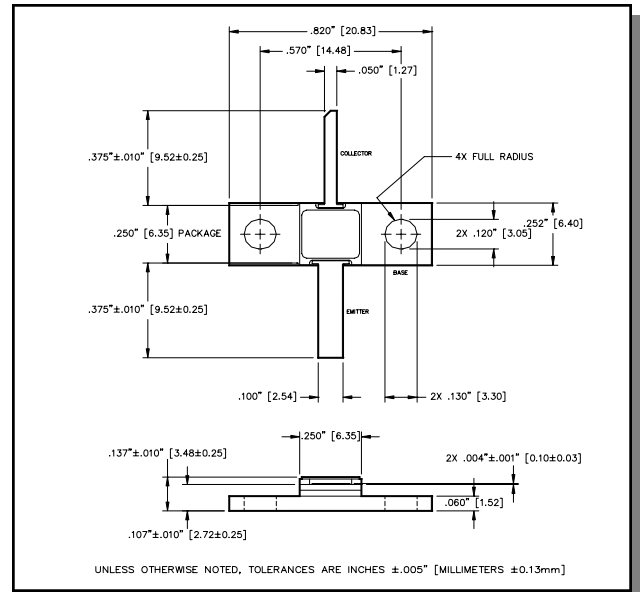
Radar Pulsed Power Transistor
20W, 1.2-1.4 GHz, 2ms Pulse, 10% Duty

M/A-COM Products
Released, 30 May 07

Features

- NPN silicon microwave power transistors
- Common base configuration
- Broadband Class C operation
- High efficiency inter-digitized geometry
- Diffused emitter ballasting resistors
- Gold metallization system
- Internal input and output impedance matching
- Hermetic metal/ceramic package
- RoHS compliant

Outline Drawing



Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	V_{CES}	70	V
Emitter-Base Voltage	V_{EBO}	3.0	V
Collector Current (Peak)	I_C	1.5	A
Power Dissipation @ +25°C	P_{TOT}	30	W
Storage Temperature	T_{STG}	-65 to +200	°C
Junction Temperature	T_J	200	°C

Electrical Specifications: $T_C = 25 \pm 5^\circ\text{C}$ (Room Ambient)

Parameter	Test Conditions	Frequency	Symbol	Min	Max	Units
Collector-Emitter Breakdown Voltage	$I_C = 12.5\text{mA}$		BV_{CES}	60	-	V
Collector-Emitter Leakage Current	$V_{CE} = 40\text{V}$		I_{CES}	-	2.5	mA
Thermal Resistance	$V_{CC} = 28\text{V}$, $P_{out} = 20\text{W}$	F = 1.2, 1.3, 1.4 GHz	$R_{TH(JC)}$	-	5.8	°C/W
Output Power	$V_{CC} = 28\text{V}$, $P_{out} = 20\text{W}$	F = 1.2, 1.3, 1.4 GHz	P_{IN}	-	2.3	W
Power Gain	$V_{CC} = 28\text{V}$, $P_{out} = 20\text{W}$	F = 1.2, 1.3, 1.4 GHz	G_P	9.5	-	dB
Collector Efficiency	$V_{CC} = 28\text{V}$, $P_{out} = 20\text{W}$	F = 1.2, 1.3, 1.4 GHz	η_C	50	-	%
Input Return Loss	$V_{CC} = 28\text{V}$, $P_{out} = 20\text{W}$	F = 1.2, 1.3, 1.4 GHz	RL	-	-6	dB
Load Mismatch Tolerance	$V_{CC} = 28\text{V}$, $P_{out} = 20\text{W}$	F = 1.2, 1.3, 1.4 GHz	VSWR-T	-	3:1	-
Load Mismatch Stability	$V_{CC} = 28\text{V}$, $P_{out} = 20\text{W}$	F = 1.2, 1.3, 1.4 GHz	VSWR-S	-	1.5:1	-

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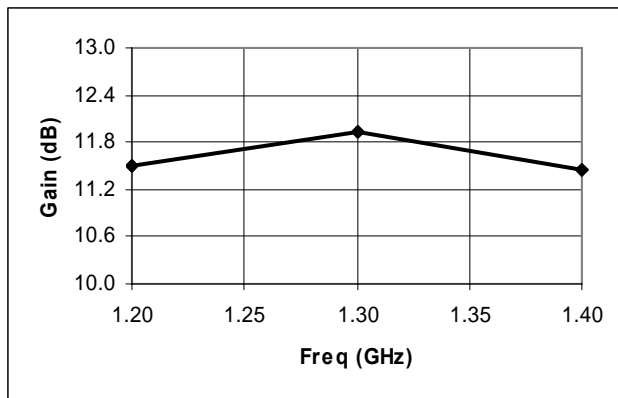
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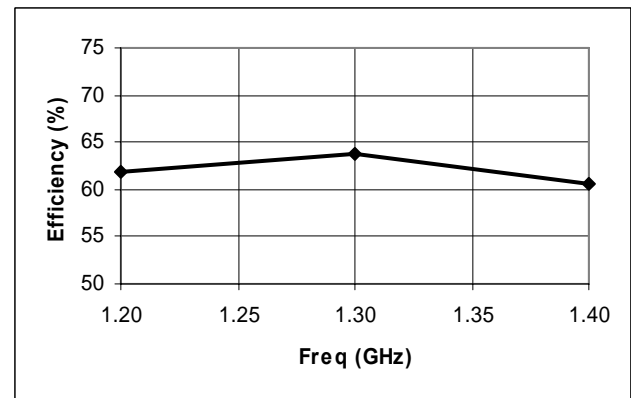
Typical RF Performance

Freq. (GHz)	Pin (W)	Pout (W)	Gain (dB)	Ic (A)	Eff (%)	RL (dB)	VSWR-S (1.5:1)	VSWR-T (3:1)
1.2	1.42	20	11.49	1.15	61.9	-20.4	S	P
1.3	1.29	20	11.92	1.12	63.7	-12.9	S	P
1.4	1.44	20	11.44	1.18	60.7	-8.0	S	P

Gain vs. Frequency

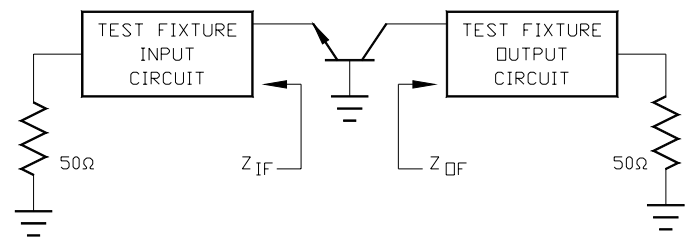


Collector Efficiency vs. Frequency



RF Test Fixture Impedance

F (GHz)	Z _{IF} (Ω)	Z _{OF} (Ω)
1.2	2.1 - j4.5	3.7 + j0.9
1.3	2.1 - j3.9	3.6 + j0.4
1.4	2.2 - j3.4	3.0 + j0.2



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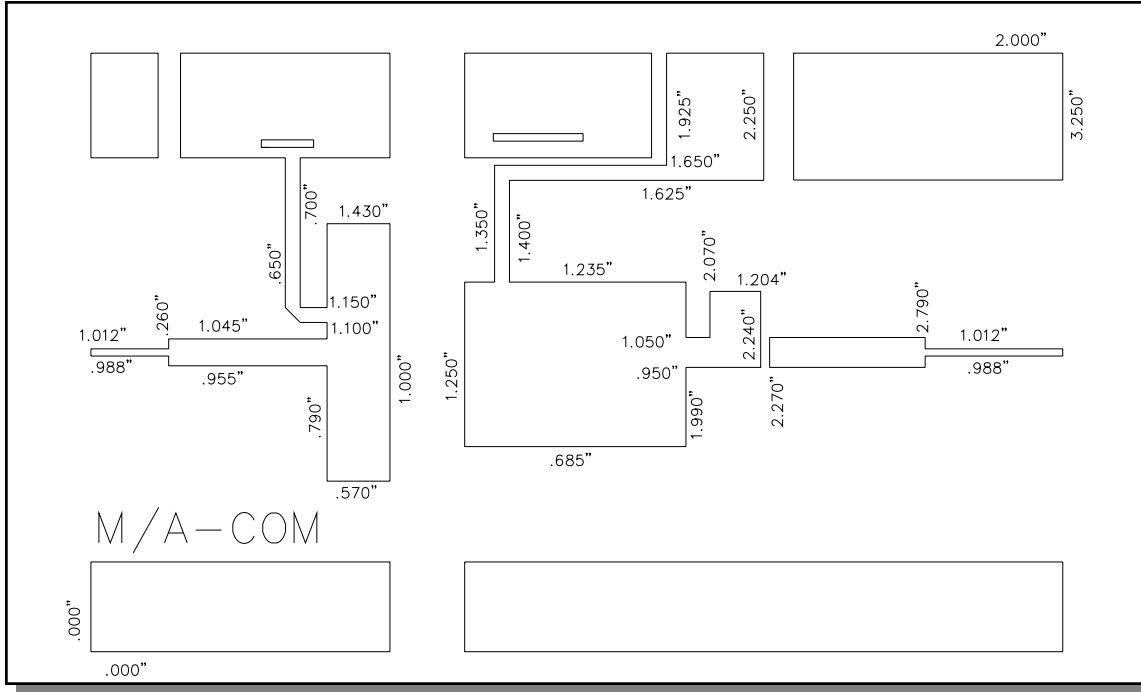
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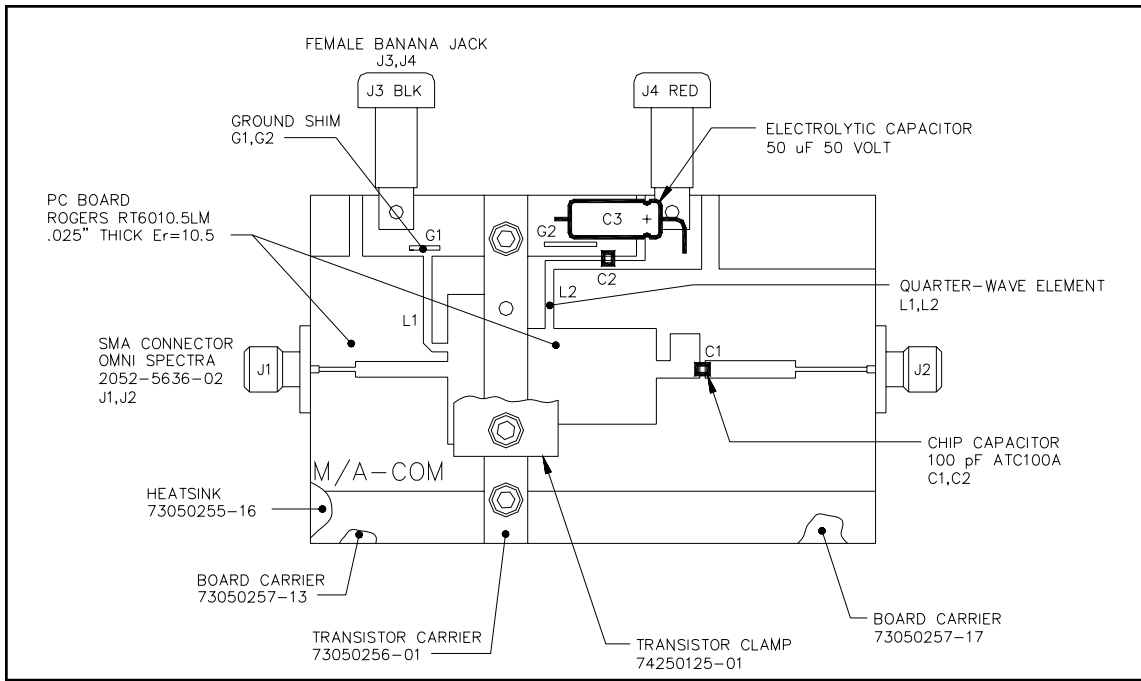
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Test Fixture Circuit Dimensions



Test Fixture Assembly



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